

Features

- Low On-resistance, $R_{on}=1.5\Omega$ when $COMx=5V$
- 1.8V Logic Compatible Control Pin
- High Off-Isolation: $-100dB @ 100KHz$
- $COMx$ Overrides VCC to Achieve True Isolation Even When Supply Is Dead
- Low Channel-to-Channel Crosstalk: $-97dB @ 100KHz$
- High Bandwidth ($-3dB @ 500MHz$) Suitable For USB2.0 High-Speed Routing
- Low Quiescent Current ($<2\mu A$) With Very Wide Supply Range ($1.5V \sim 5.5V$)
- Small Packaging: QFN2015-10L

Applications

- Mobile Phones, Tablets and Notebooks
- USB Type-C Mic/Gnd Switch
- Audio, Video, UART, USB2.0 Signal and Supply Routing
- Telecom Signal Switching
- Sample and Hold Systems
- Signal Gating, Multiplexer / Demultiplexer

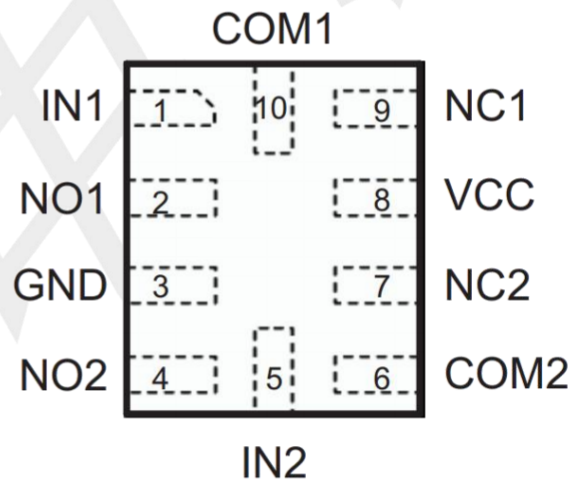
General Description

The is a dual SPDT low on-resistance analog switch. It can operate from a single 1.5V to 5.5V power supply.

The device offers low ON-state resistance and excellent ON-state resistance matching with break-before-make feature, to prevent signal distortion during the transferring of a signal from one channel to another.

The device is capable of true isolation. Even when $COMx$ overrides VCC , very little current will flow back to the supply.

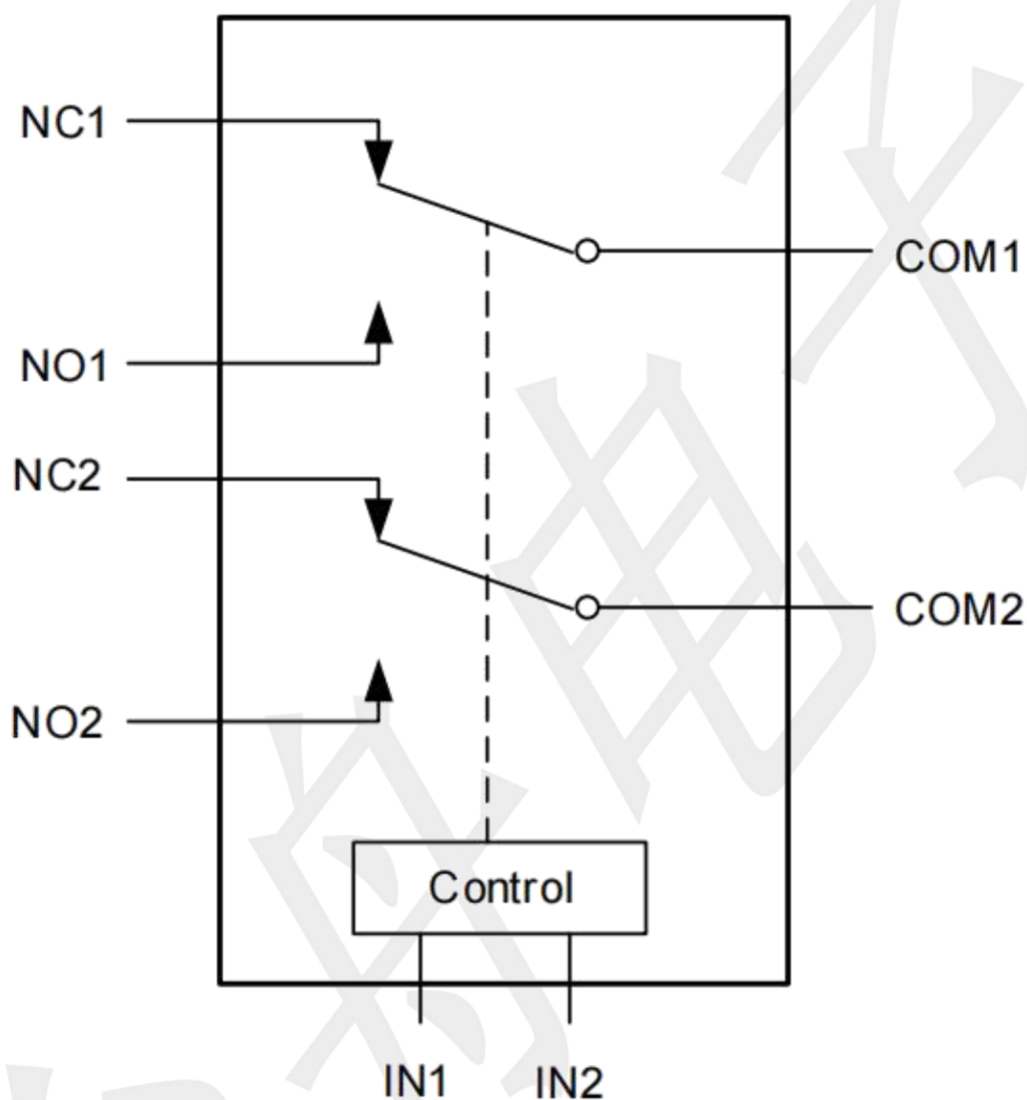
PIN CONFIGURATIONS



PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	IN1	Digital control to connect COM to NO or NC
2	NO 1	Analog/Digital Signal Ports (Normally closed)
3	GND	Ground
4	NO 2	Analog/Digital Signal Ports (Normally closed)
5	IN2	Digital control to connect COM to NO or NC
6	COM2	Port 2 common data terminal, Connect to NC2 or NO2 according to SEL logic
7	NC 2	Analog/Digital Signal Ports (Normally open)
8	VCC	Supply voltage
9	NC 1	Analog/Digital Signal Ports (Normally open)
10	COM1	Port 1 common data terminal, Connect to NC1 or NO1 according to SEL logic

BLOCK DIAGRAM



Function Table

Logic Input(IN _x)	Function
0	NC1=COM1 and NC2=COM2
1	NO1=COM1 and NO2=COM2

Note: X= 1 or 2

Absolute Maximum Ratings

(Unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V _{CC}	-0.3 ~ +6.5	V
Input Voltage	V _{IN}	-0.3 ~ +6.5	V
Continuous Current Through NO, NC, COM		±100	mA
Peak Current Through NO, NC, COM (pulsed at 1ms 50% duty cycle)		±200	mA
Storage Temperature Range	T _{STG}	-55 ~ +150	°C
Operating Junction Temperature	T _J	150	°C
Lead Temperature (Soldering, 10 seconds)	T _L	260	°C
Power Dissipation	P _D	250	mW

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Recommend operating ratings

(Unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage Operating	V _{CC}	1.5 ~ 5.5	V
Control Input Voltage	V _{IN}	-0.3 ~ 5.5	V
Input Signal Voltage	V _{COM}	-0.3 ~ 5.5	V
Operating Temperature	T _A	-40 ~ +85	°C
Junction to Ambient	R _{θJA}	360	°C/W

DC Electrical Characteristics (TA = 25°C, VC = +3.3V, unless otherwise specified)

PARAMETER	SYMBOL	TEST Conditions	MIN	TYP	MAX	UNIT
High-Level Input Voltage	VIH	VCC=3.3V ~ 5.5V	1.6	--	--	V
		VCC=1.5V ~ 3.3V	1.4	--	--	V
Low-Level Input Voltage	VIL	VCC=3.3V ~ 5.5V	--	--	0.6	V
		VCC=1.5V ~ 3.3V	--	--	0.4	V
Supply quiescent current	ICC	IA=0, VSEL=0 or VSEL=VCC	--	--	1.0	uA
Increase in ICC per input	ICCT	IA=0, VCC=4.5V VSEL>1.8 or VSEL<0.5	--	--	1.0	uA
Off state leakage from COMx to NCx (or NOx)	ICOMx	VCOM = 5.5V, VNC(or NO) = 0V	--	--	±2.0	uA
On-Resistance	RON1	VA=0 ~ 0.5V, IA=30mA	--	3.6	3.9	Ω
	RON2	VA=0.5 ~ 2.0V, IA=30mA	--	3.0	3.5	Ω
	RON3	VA=2.0 ~ 4.0V, IA=30mA	--	2.5	3.5	Ω
	RON4	VA=4.0 ~ 5.5V, IA=30mA	--	1.5	1.8	Ω
On-Resistance Flatness	RFLAT1	VA=0 ~ 0.5V, IA=30mA	--	1.6	--	Ω
	RFLAT2	VA=0.5 ~ 2.0V, IA=30mA	--	0.7	--	Ω
	RFLAT3	VA=2.0 ~ 4.0V, IA=30mA	--	0.5	--	Ω
	RFLAT4	VA=4.0 ~ 5.5V, IA=30mA	--	0.3	--	Ω
On-Resistance Matching Between Channels	ΔRON	VA=0~5.5V, IA=30mA	--	0.1	0.2	Ω

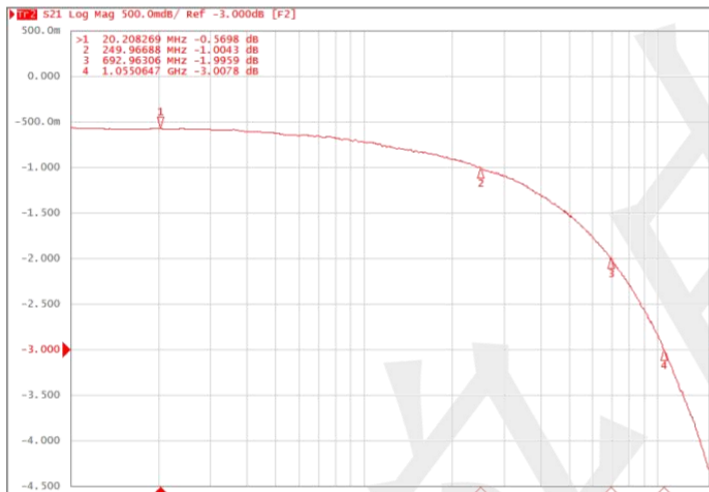
AC Electronics Characteristics (Ta=25°C, VCC=+3.3V, unless otherwise noted)

PARAMETER	SYMBOL	TEST Conditions	MIN	TYP	MAX	UNIT
Turn-On Time	TON	VA=1.5V, CL=35pF, RL=50Ω	--	200	--	ns
Turn-Off Time	TOFF	VA=1.5V, CL=35pF, RL=50Ω	--	200	--	ns
Break-Before-Make time	TBBM	VA=1.5V, CL=35pF, RL=50Ω	--	500	--	ns
-3dB Bandwidth	BW	RL=50Ω, CL=5pF	--	500	--	MHz
		RL=50Ω, CL=0pF	--	700	--	MHz
Off isolation	OIRR	F=1KHz, RL=50Ω	--	-81	--	dB
		F=10KHz, RL=50Ω	--	-80	--	dB
Crosstalk	Xtalk	F=1KHz, RL=50Ω	--	-83	--	dB
		F=10KHz, RL=50Ω	--	-82	--	dB
Total Harmonic Distortion	THD	F=20Hz to 20KHz VA=600mVp-p @RL=32Ω	--	-80	--	dB

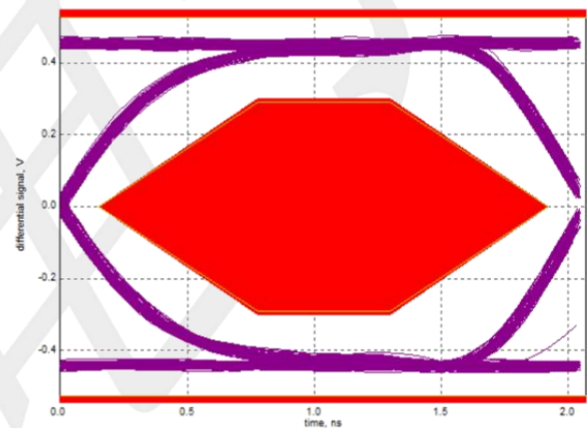
Capacitance ($T_a=25^\circ\text{C}$, $V_{CC}=+3.3\text{V}$, unless otherwise noted)

PARAMETER	SYMBOL	TEST Conditions	MIN	TYP	MAX	UNIT
Off capacitance	C_{OFF}	$F=100\text{KHz}$,	--	5.0	--	pF
On capacitance	C_{ON}	$F=100\text{KHz}$,	--	7.0	--	pF

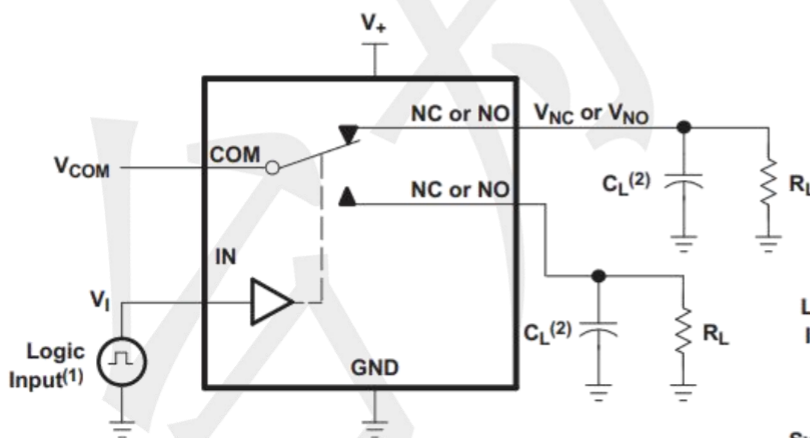
Typical Characteristics ($T_a=25^\circ\text{C}$, $V_{CC}=3.3\text{V}$, unless otherwise noted)



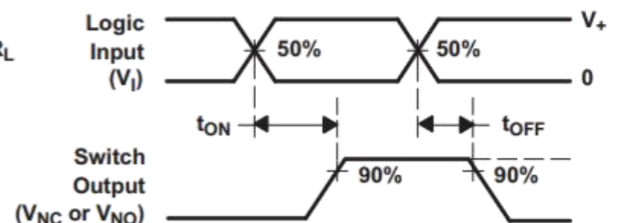
Bandwidth



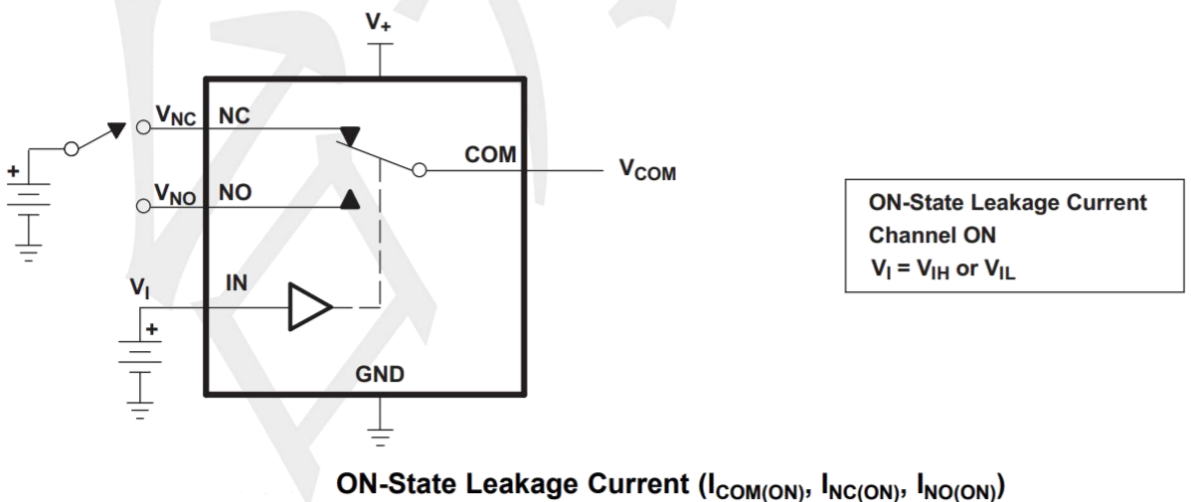
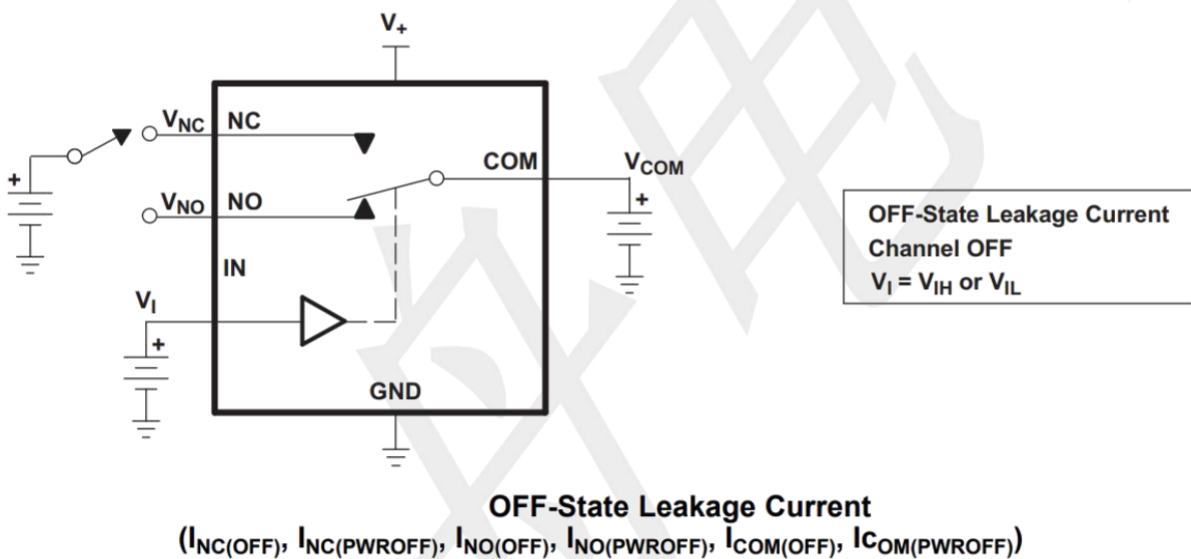
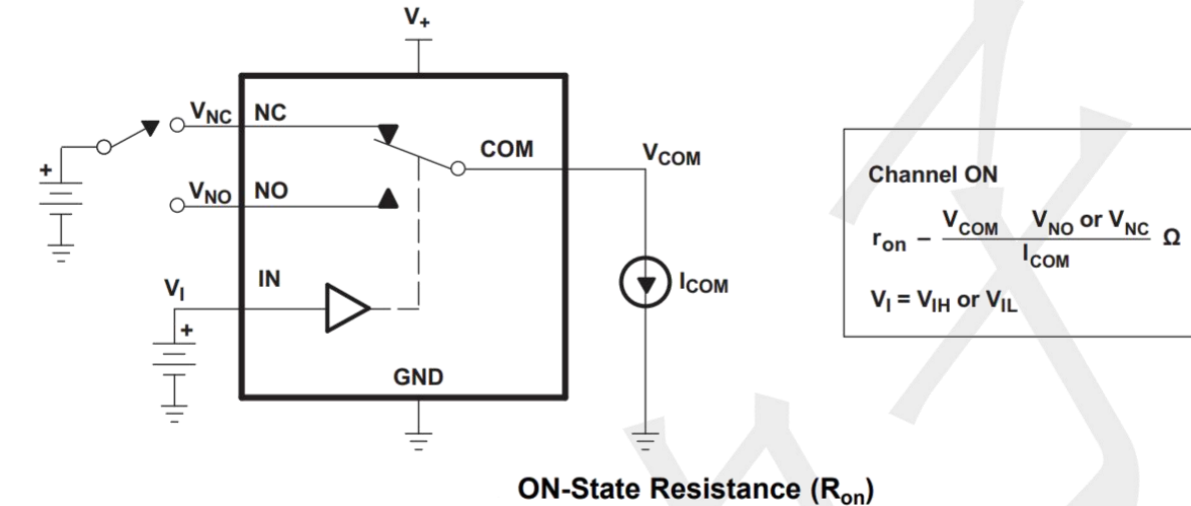
Eye Diagram (480Mbps)



TEST	R_L	C_L	V_{COM}
t_{ON}	50Ω	35 pF	V_+
t_{OFF}	50Ω	35 pF	V_+

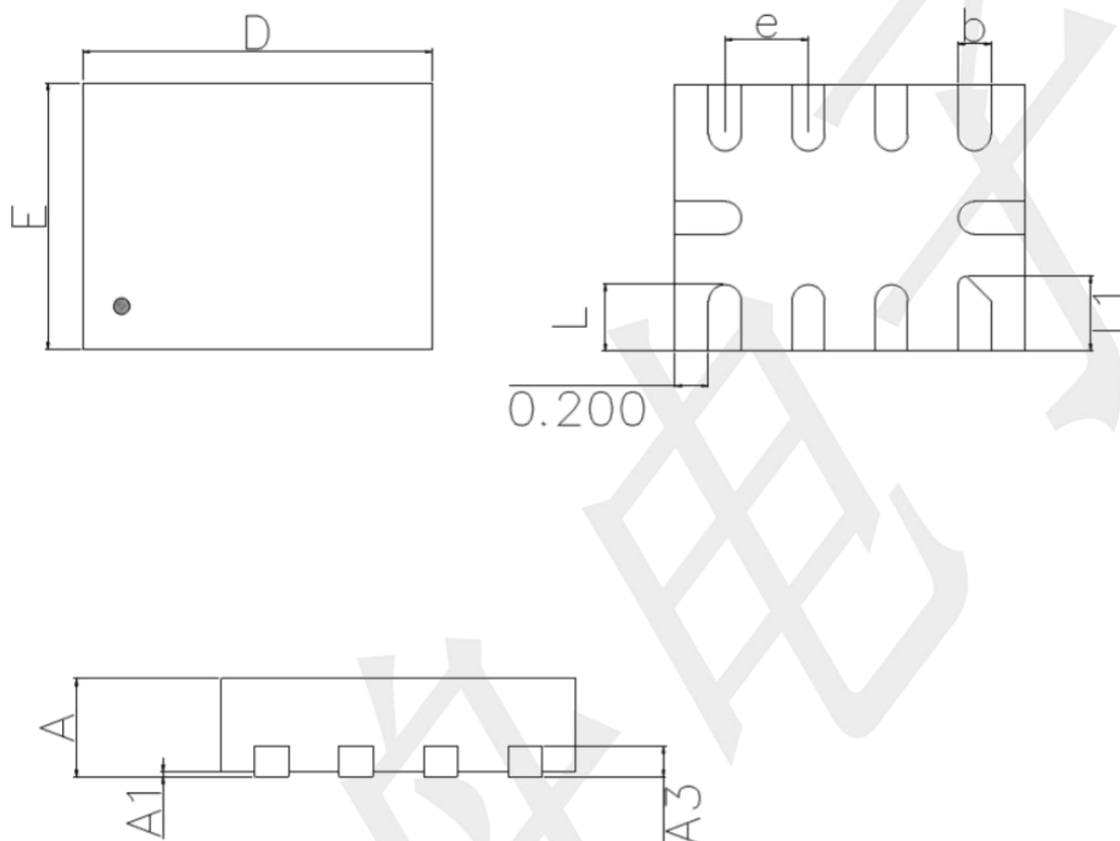


Typical Characteristics ($T_a=25^{\circ}\text{C}$, $V_{CC}=3.3\text{V}$, unless otherwise noted)



Package information

QFN2015-10L (Unit: mm)



Symbol	Dimension in Millimeters		
	Min.	Typ.	Max.
A	0.500	0.550	0.600
A1	0.000		0.050
A3	0.150 Ref.		
D	1.950	2.000	2.050
E	1.450	1.500	1.550
b	0.150	0.200	0.250
e	0.500 (BSC)		
L	0.300	0.350	0.400
L1	0.350	0.400	0.450